CPH6538



http://onsemi.com

Bipolar Transistor 30V, 0.7A, Low VCE(sat) NPN Dual CPH6

Features

- · Small-sized package with two NPN transistors (30C02CH equivalency) contained in one package
- · VCEO=30V, IC=0.7A
- Low Collector-to-Emitter Saturation Voltage V_{CE}(sat)=85mV(typ.)@I_C=0.2A
- High-speed switching tf=40ns(typ.)@IC=0.3A
- · Halogen free Compliance

Specifications

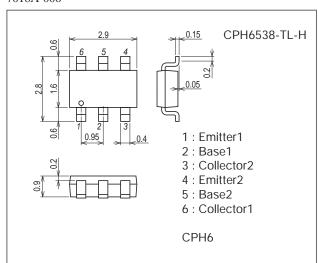
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		40	V
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	V _{EBO}		5	V
Collector Current	IC		700	mA
Collector Current (Pulse)	ICP		1.4	Α
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm) 1unit	0.6	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7018A-006



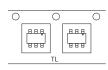
Product & Package Information

• Package : CPH6

• JEITA, JEDEC : SC-74, SOT-26, SOT-457

• Minimum Packing Quantity : 3,000 pcs./reel

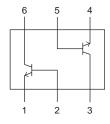
Packing Type: TL



Marking



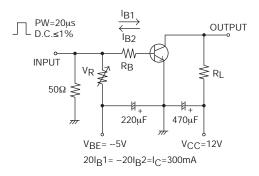
Electrical Connection



Electrical Characteristics at Ta=25°C

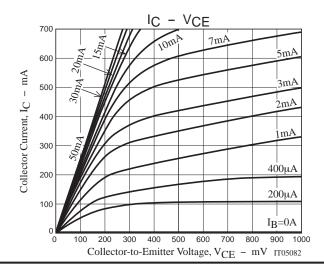
Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	VCB=30V, IE=0A			100	nA	
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			100	nA	
DC Current Gain	hFE	V _{CE} =2V, I _C =50mA	300		800		
Gain-Bandwidth Product	fŢ	V _{CE} =2V, I _C =50mA		540		MHz	
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		3.3		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =200mA, I _B =10mA		85	190	mV	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =200mA, I _B =10mA		0.9	1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0A	40			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	30			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0A	5			V	
Turn-On Time	ton			35		ns	
Storage Time	t _{stg}	See specified Test Circuit.		255		ns	
Fall Time	tf			40		ns	

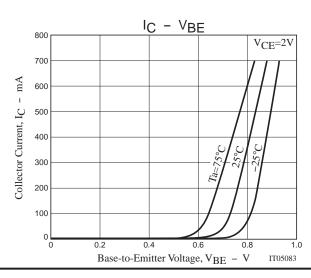
Switching Time Test Circuit

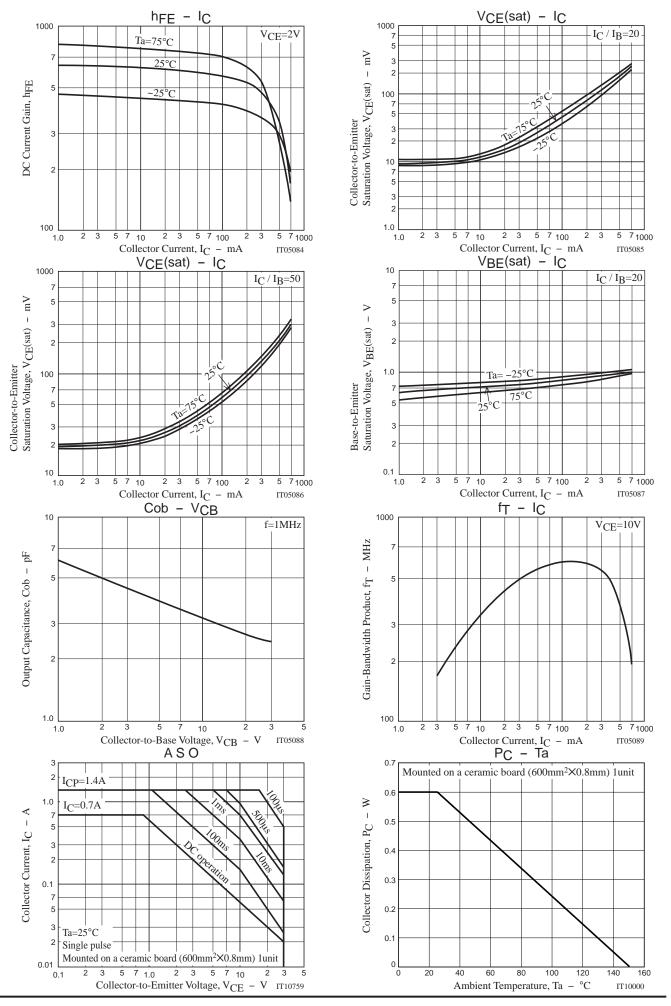


Ordering Information

Device	Package	Shipping	memo	
CPH6538-TL-H	CPH6538-TL-H CPH6		Pb Free and Halogen Free	





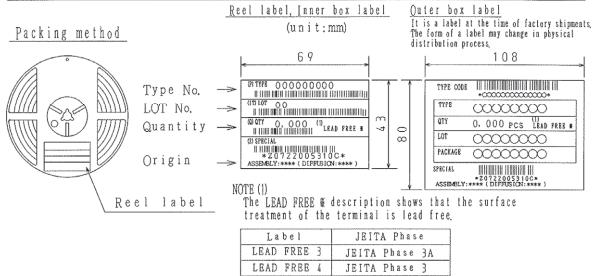


Embossed Taping Specification

CPH6538-TL-H

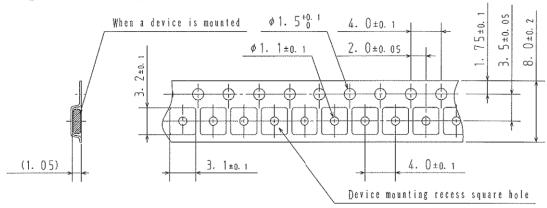
1. Packing Format

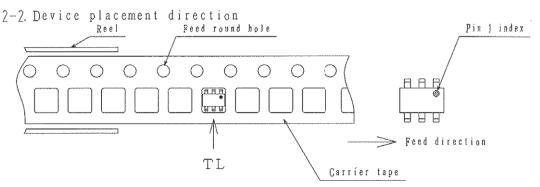
Package Name	Carrier Tape	Maximum Number of devices contained (pcs)				
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
СРН6	СРН6	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210



2. Taping configuration

2-1. Carrier tape size (unit:mm)

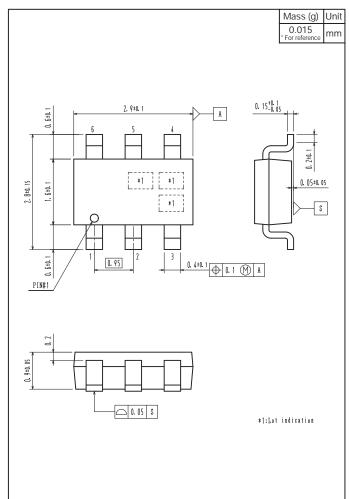




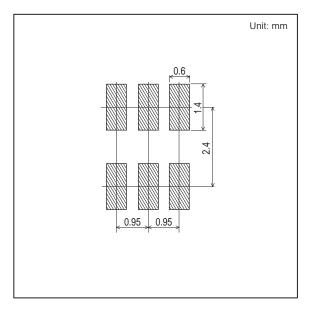
Those with pin 1 index on the feed hole side · · · · · TL

Outline Drawing

СРН6538-ТL-Н



Land Pattern Example



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